

DC-DC CONVERTER CONTROL CIRCUITS

- OUTPUT SWITCH CURRENT IN EXCESS OF 1.5A
- 2% REFERENCE ACCURACY
- LOW QUIESCENT CURRENT: 2.5mA (TYP.)
- OPERATING FROM 3V TO 40V
- FREQUENCY OPERATION TO 100KHz
- ACTIVE CURRENT LIMITING

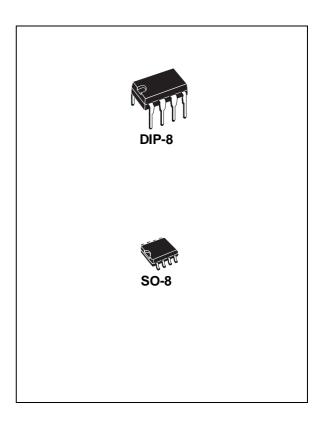
DESCRIPTION

The MC34063A/E series is a monolithic control circuit delivering the main functions for DC-DC voltage converting.

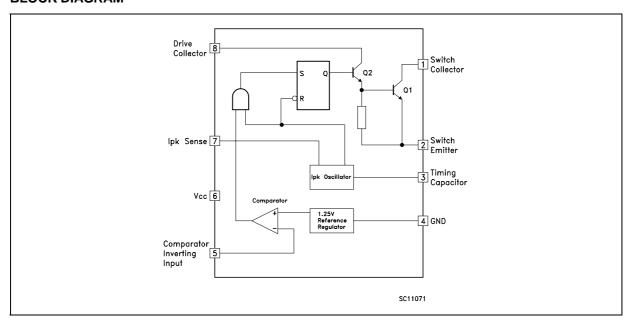
The device contains an internal temperature compensated reference, comparator, duty cycle controlled oscillator with an active current limit circuit, driver and high current output switch.

Output voltage is adjustable through two external resistors with a 2% reference accuracy.

Employing a minimum number of external components the MC34063A/E devices series is designed for Step-Down, Step-Up and Voltage-Inverting applications.



BLOCK DIAGRAM



March 2001 1/15

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vcc	Power Supply Voltage	50	V
V_{ir}	Comparator Input Voltage Range	-0.3 to 40	V
Vswc	Switch Collector Voltage	40	V
V_{SWE}	Switch Emitter Voltage (VSWC = 40V)	40	V
Vce	Switch Collector toEmitter Voltage	40	V
V_{dc}	Driver Collector Voltage	40	V
I _{dc}	Driver Collector Current	100	mA
I _{SW}	Switch Current	1.5	Α
P _{tot}	Power Dissipation at T _{amb} = 25 °C (for Plastic Package) (for SOIC Package)	1.25 0.625	W
Тор	Operating Ambient Temperature Range (for AC and EC SERIES) (for AB SERIES) (for EB SERIES)	0 to 70 - 40 to 85 - 40 to 125	°C °C °C
T _{stg}	Storage Temperature Range	- 40 to 150	°C

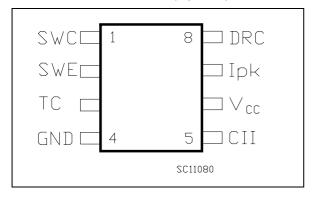
Absolute Maximum Rating are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

THERMAL DATA

Symbol	Parameter	DIP-8	SO-8	Unit
R _{thj-amb}	Thermal Resistance Junction-ambient (*) Max	100	160	°C/W

^(*) This value depends from thermal design of PCB on which the device is mounted.

CONNECTION DIAGRAM (top view)



PIN CONNECTIONS

Pin No	Symbol	Name and Function
1	SWC	Switch Collector
2	SWE	Switch Emitter
3	TC	Timing Capacitor
4	GND	Ground
5	CII	Comparator Inverting Input
6	Vcc	Voltage Supply
7	I _{pk}	I _{pk} Sense
8	DRC	Voltage Driver Collector

ORDERING NUMBERS

Туре	DIP-8	SO-8	SO-8 (tape & reel)
MC34063AB (*)	MC34063ABN	MC34063ABD	MC34063ABD-TR
MC34063AC (*)	MC34063ACN	MC34063ACD	MC34063ACD-TR
MC34063EB	MC34063EBN	MC34063EBD	MC34063EBD-TR
MC34063EC	MC34063ECN	MC34063ECD	MC34063ECD-TR

(*) The "A" version is not recommended for new designs.

ELECTRICAL CHARACTERISTICS (Refer to the test circuits, $V_{CC} = 5V$, $T_a = T_{LOW}$ to T_{HIGH} , unless otherwise specified, see note 2)

OSCILLATOR

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
fosc	Frequency	$V_{pin5} = 0 \text{ V}$ $C_T = 1 \text{ nF}$ $T_a = 25 ^{\circ}\text{C}$	24	33	42	KHz
I _{chg}	Charge Currernt	$V_{CC} = 5 \text{ to } 40 \text{ V}$ $T_a = 25 {}^{\circ}\text{C}$	24	33	42	μΑ
I _{dischg}	Discharge Current	$V_{CC} = 5 \text{ to } 40 \text{ V}$ $T_a = 25 {}^{\circ}\text{C}$	140	200	260	μΑ
I _{dischg} /I _{chg}	Discharge to Charge Current Ratio	Pin 7 = V_{CC} $T_a = 25$ °C	5.2	6.2	7.5	
V _{ipk(sense)}	Current Limit Sense Voltage	$I_{chg} = I_{dischg}$ $T_a = 25$ °C	250	300	350	mV

OUTPUT SWITCH

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{CE(sat)}	Saturation Voltage, Darlington Connection	I _{SW} = 1 A Pins 1, 8 connected		1	1.3	V
$V_{CE(sat)}$	Saturation Voltage	I_{SW} = 1 A R_{pin8} = 82 Ω to V_{CC} , Forced β ~ 20		0.45	0.7	V
h _{FE}	DC Current Gain	$I_{SW} = 1 \text{ A}$ $V_{CE} = 5 \text{ V}$ $T_a = 25 ^{\circ}\text{C}$	50	120		
I _{C(off)}	Collector Off-State Current	V _{CE} = 40 V		0.01	100	μΑ

COMPARATOR

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V_{th}	Threshold Voltage	$T_a = 25$ °C $T_a = T_{LOW}$ to T_{HIGH}	1.225 1.21	1.25	1.275 1.29	> >
Reg _{line}	Threshold Voltage Line Regulation	V _{CC} = 3 to 40 V		1	5	mV
I _{IB}	Input Bias Current	V _{IN} = 0 V		-5	-400	nA

TOTAL DEVICE

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Icc	Supply Current	$\begin{split} &V_{CC}=5\text{ to }40\text{ V} &C_{T}=1\text{ nF} \\ &\text{Pin }7=V_{CC} &V_{pin5}>V_{th} &\text{Pin }2=GND \\ &\text{Remaining pins open} \\ &\text{for } \textbf{MC34063A} \\ &\text{for } \textbf{MC34063E} \end{split}$		2.5 1.5	4 4	mA mA
V _{START-UP}	Start-up Voltage (note 4)	$T_a = 25$ °C $C_T = 1 \mu\text{F}$ Pin 5 = 0 V for MC34063A for MC34063E		2.1 1.5		V V

¹⁾ Maximum package power dissipation limit must be observed.

²⁾ TLOW = 0 °C, THIGH = 70 °C (AC and EC series); TLOW = -40 °C, THIGH = 85 °C (AB series); TLOW = -40 °C, THIGH = 125 °C (EB series).

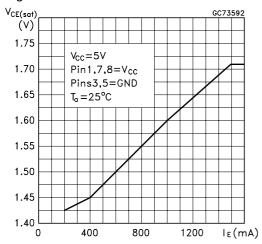
³⁾ If Darlington configuration is not used, care must be taken to avoid deep saturation of output switch. The resulting switch-off time may be adversely affected. In a Darlington configuration the following output driver condition is suggested:

Forced β of output current switch = $I_{COUTPUT}/(I_{CDRIVER} - 1 m A^*) \geq 10$ * Current less due to a built in $1 K \Omega$ antileakage resistor.

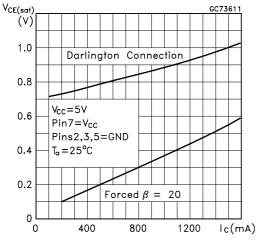
⁴⁾ Start-up Voltage is the minimum Power Supply Voltage at which the internal oscillator begins to work.

TYPICAL ELECTRICAL CHARACTERISTICS

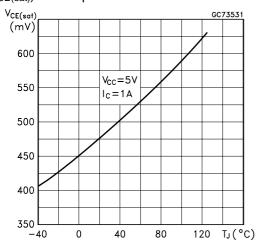
Emitter Follower Configuration Output Saturation Voltage vs Emitter Current



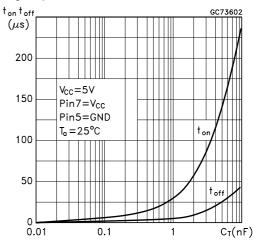
Common Emitter Configuration Output Switch Saturation Voltage vs Collector Current



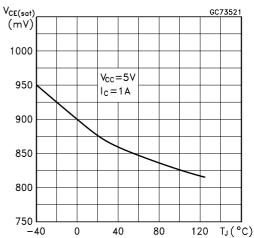
Power Collector Emitter Saturation Voltage (V_{CE(sat)}) vs Temperature



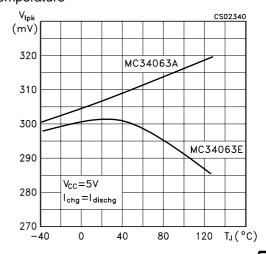
Output Switch ON-OFF Time vs Oscillator Timing Capacitor



Darlington Configuration Collector Emitter Saturation Voltage (V_{CE(sat)}) vs Temperature

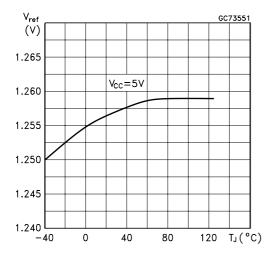


Current Limit Sense Voltage Voltage (V_{ipk}) vs Temperature

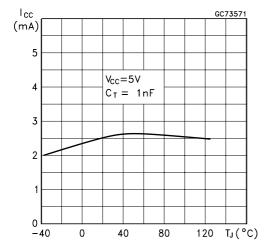


TYPICAL ELECTRICAL CHARACTERISTICS (Continued)

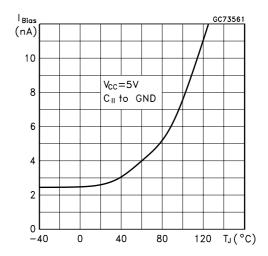
Reference Voltage vs Temperature



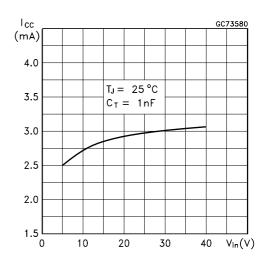
Supply Current vs Temperature



Bias Current vs Temperature

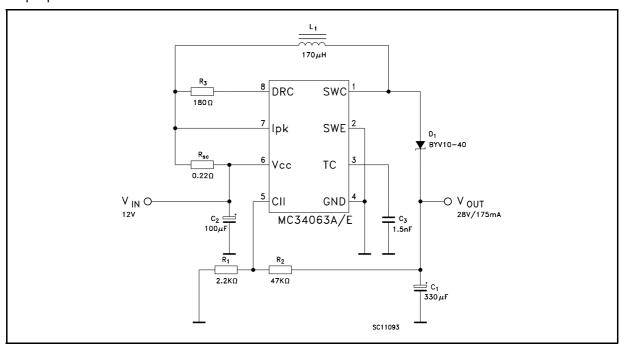


Supply Current vs Input Voltage

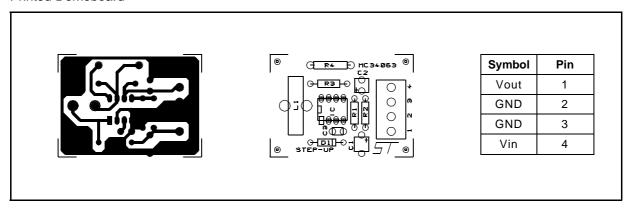


TYPICAL APPLICATION CIRCUIT

Step-Up Converter



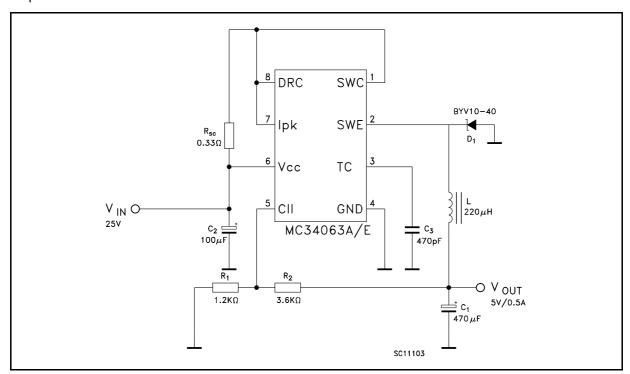
Printed Demoboard



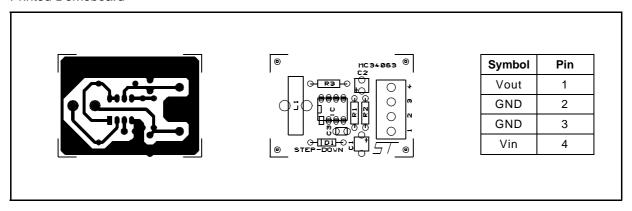
Test Condition (Vout = 28V)

Test	Conditions	Value (Typ.)	Unit
Line Regulation	$V_{IN} = 8 \text{ to } 16V, I_O = 175 \text{ mA}$	30	mV
Load Regulation	$V_{IN} = 12V$, $I_O = 75$ to 175 mA	10	mV
Output Ripple	V _{IN} = 12V, I _O = 175 mA	300	mV
Efficency	$V_{IN} = 12V$, $I_{O} = 175 \text{ mA}$	89	%

Step-Down Converter



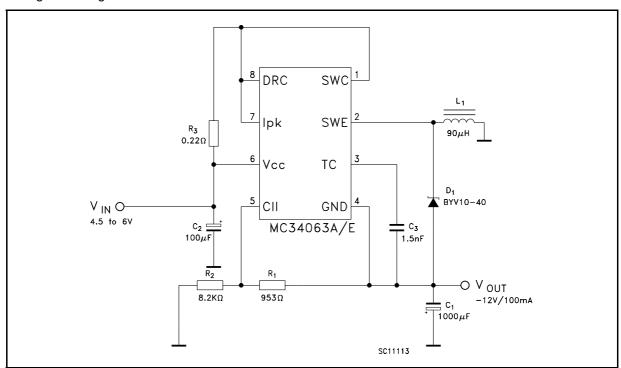
Printed Demoboard



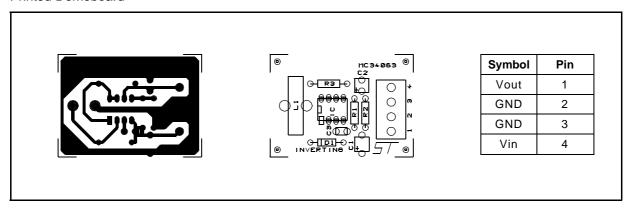
Test Condition (Vout = 5V)

Test	Conditions		Unit
Line Regulation	$V_{IN} = 15 \text{ to } 25V, I_O = 500 \text{ mA}$	5	mV
Load Regulation	$V_{IN} = 25V$, $I_O = 50$ to 500 mA	30	mV
Output Ripple	$V_{IN} = 25V$, $I_O = 500 \text{ mA}$	100	mV
Efficency	$V_{IN} = 25V$, $I_O = 500 \text{ mA}$	80	%
Isc	$V_{IN} = 25V$, $R_{LOAD} = 0.1\Omega$	1.2	Α

Voltage Inverting Converter



Printed Demoboard



Test Condition (Vout = -12V)

Test	Conditions	Value (Typ.)	Unit
Line Regulation	$V_{IN} = 4.5 \text{ to 6V}, I_{O} = 100 \text{ mA}$	15	mV
Load Regulation	$V_{IN} = 5V$, $I_O = 10 \text{ to } 100 \text{ mA}$	20	mV
Output Ripple	$V_{IN} = 5V$, $I_O = 100 \text{ mA}$	230	mV
Efficency	$V_{IN} = 5V$, $I_O = 100 \text{ mA}$	58	%
Isc	$V_{IN} = 5V$, $R_{ILOAD} = 0.1\Omega$	0.9	Α

Calculation

Parameter	Step-Up (Discontinuos mode)	Step-Down (Continuos mode)	Voltage Inverting (Discontinuos mode)
$t_{\text{on}}/t_{\text{off}}$	$\frac{V_{out} + V_F - V_{in(min)}}{V_{in(min)} - V_{sat}}$	$\frac{V_{out} + V_F}{V_{in(min)} - V_{sat} - V_{out}}$	$\frac{ V_{out} + V_F}{V_{in} - V_{sat}}$
(t _{on} + t _{off})max	1/f _{min}	1/f _{min}	1/f _{min}
Ст	4.5x10 ⁻⁵ t _{on}	4.5x10 ⁻⁵ t _{on}	4.5x10 ⁻⁵ t _{on}
I _{PK(switch)}	$2I_{out(max)}[(t_{on}/t_{off})+1]$	2I _{out(max)}	$2I_{out(max)}[(t_{on}/t_{off})+1]$
R _{SC}	0.3/I _{PK(switch)}	0.3/I _{PK(switch)}	0.3/I _{PK(switch)}
Со	$\cong \frac{I_{out} t_{on}}{V_{ripple}(p-p)}$	$\frac{I_{PK(switch)}(t_{on} + t_{off})}{8V_{ripple(p-p)}}$	$\cong \frac{I_{out}t_{on}}{V_{ripple(p-p)}}$
L(min)	$\frac{V_{in(min)} - V_{sat}}{I_{PK (switch)}} t_{on (max)}$	$\frac{V_{\text{in(min)}} - V_{\text{sat}} - V_{\text{out}}}{I_{\text{PK (switch)}}} t_{\text{on (max)}}$	$\frac{V_{\text{in(min)}} - V_{\text{sat}}}{I_{\text{PK(switch)}}} t_{\text{on (max)}}$

 V_{sat} = Saturation voltage of the output switch

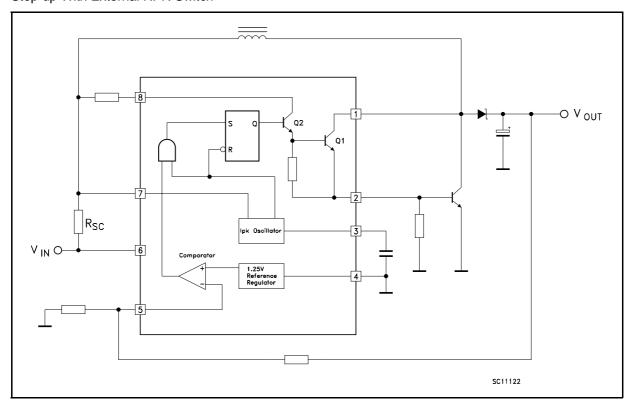
V_F = Foward voltage drop of the output rectifier
THE FOLLOWING POWER SUPPLY CHARACTERISTICS MUST BE CHOSEN:

Vin = Nominal input voltage

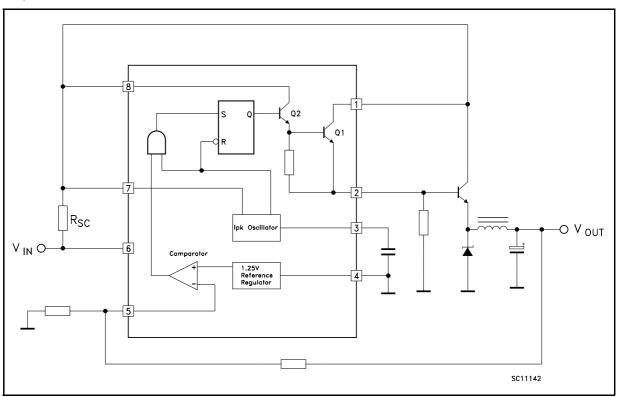
 V_{out} = Desired output voltage, $|V_{out}|$ = 1.25(1+R₂/R₁)

 $V_{\text{out}} = \text{Desired output Voltage}, |V_{\text{out}}| = 1.25(1+R_2/R_1)$ $I_{\text{out}} = \text{Desired output current}$ $f_{\text{min}} = \text{Minimum desired output switching frequency at the selected values of Vin and Io}$ $V_{\text{ripple}} = \text{Desired peak to peak output ripple voltage}. In practice, the calculated capacitor value will and to be increased due to its equivalent$ series resistance and board layout. The ripple voltage should be kept to a low value since it will directly affect the line and load regulation.

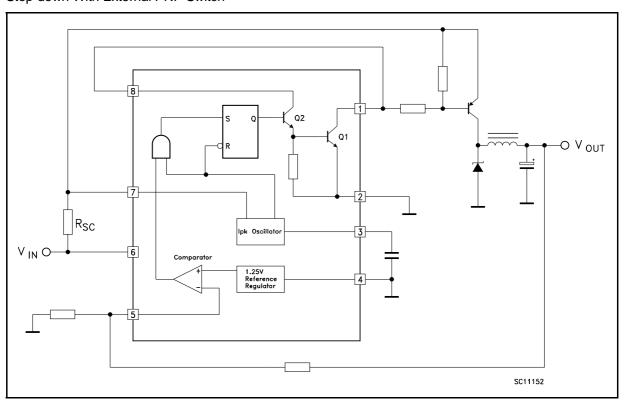
Step-up With External NPN Switch



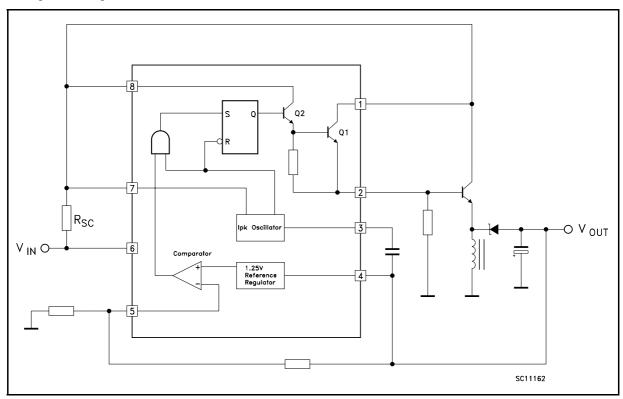
Step-down With External NPN Switch



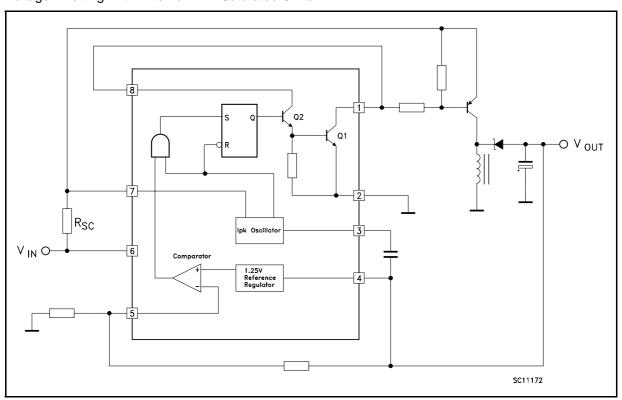
Step-down With External PNP Switch



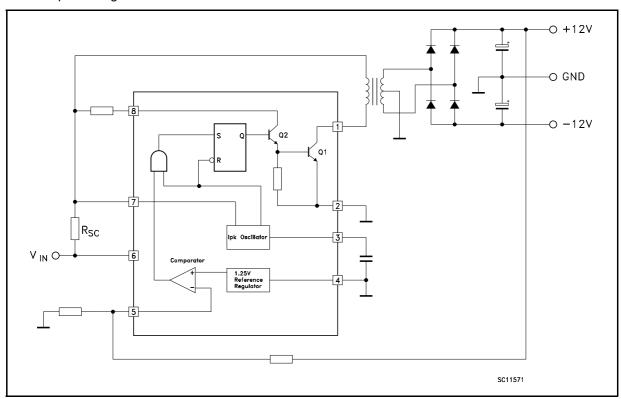
Voltage Inverting With External NPN Switch



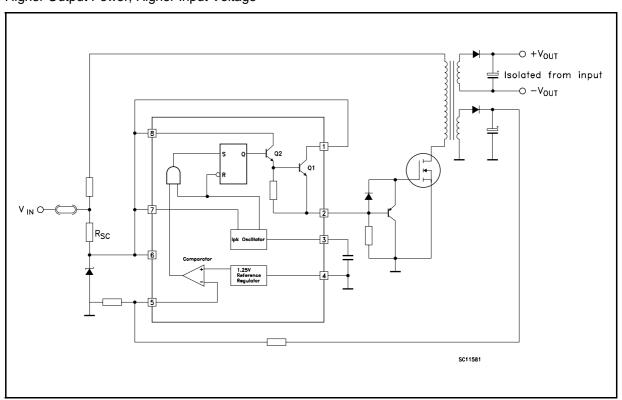
Voltage Inverting With External PNP Saturated Switch



Dual Output Voltage

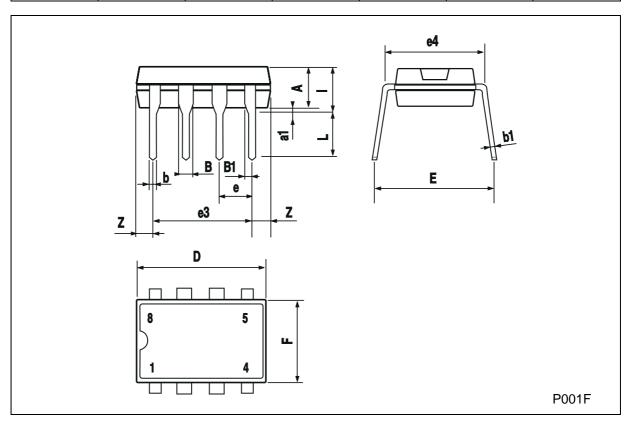


Higher Output Power, Higher Input Voltage



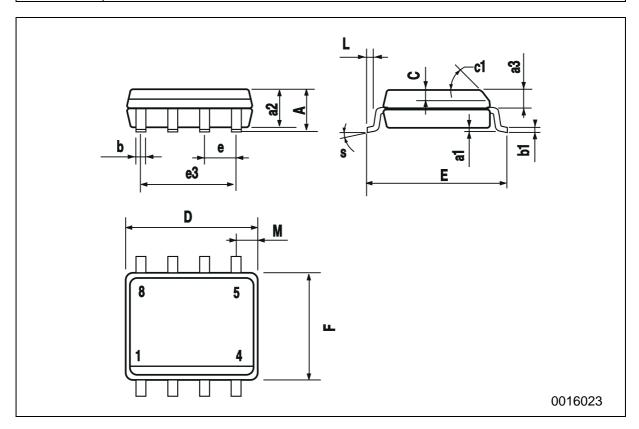
Plastic DIP-8 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α		3.3			0.130	
a1	0.7			0.028		
В	1.39		1.65	0.055		0.065
B1	0.91		1.04	0.036		0.041
b		0.5			0.020	
b1	0.38		0.5	0.015		0.020
D			9.8			0.386
Е		8.8			0.346	
е		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			7.1			0.280
ı			4.8			0.189
L		3.3			0.130	
Z	0.44		1.6	0.017		0.063



SO-8 MECHANICAL DATA

DIM.	mm			inch				
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.		
Α			1.75			0.068		
a1	0.1		0.25	0.003		0.009		
a2			1.65			0.064		
a3	0.65		0.85	0.025		0.033		
b	0.35		0.48	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С	0.25		0.5	0.010		0.019		
c1	45 (typ.)							
D	4.8		5.0	0.188		0.196		
Е	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		3.81			0.150			
F	3.8		4.0	0.14		0.157		
L	0.4		1.27	0.015		0.050		
М			0.6			0.023		
S	8 (max.)							



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